

macros. WriteBack and Read/Write can be performed in the same macro within the same cycle.

BRIEF DESCRIPTION OF THE DRAWINGS

These and other features of the present invention will become apparent from the accompanying detailed description and drawings, wherein:

including Fig. 1A, Fig. 1B and Fig. 1C

Fig. 1 shows exemplary embodiments of DRAM primary sense amplifiers with data storage and data write-back capability, and two amplification stages;

Fig. 2 shows an exemplary embodiment of a DRAM primary sense amplifier with data storage and data write-back capability;

Fig. 3 shows an exemplary embodiment of a DRAM secondary sense amplifier with two amplification stages;

Fig. 4 shows examples of executed operation and timing of the pipelined architecture DRAM;

including Fig. 5A and Fig. 5B

Fig. 5 shows waveform examples on various nodes of the pipelined architecture

DRAM;

including Fig. 6A and Fig. 6B

Fig. 6. shows exemplary embodiments of various modular DRAM size increases;

and

Fig. 7. shows an exemplary floorplan of a two dimensional growable Read/Write/WriteBack DRAM.